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**FDY2000PZ** Dual P-Channel (- 2.5V) Specified PowerTrench<sup>®</sup> MOSFET **General Description** 

FAIRCHILD SEMICONDUCTOR

# Features

This Dual P-Channel MOSFET has been designed using Fairchild Semiconductor's advanced Power Trench process to optimize the  $R_{\text{DS(ON)}} \textcircled{O} V_{\text{GS}} = -2.5v.$ 

6

## **Applications**

1

• Li-Ion Battery Pack

2

3



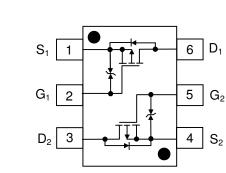
5

4

•  $-350 \text{ mA}, -20 \text{ V} \text{ R}_{\text{DS(ON)}} = 1.2 \ \Omega \ @ \text{V}_{\text{GS}} = -4.5 \text{ V}$  $R_{\text{DS(ON)}} = 1.6 \ \Omega \ @ \ V_{\text{GS}} = - \ 2.5 \ V$ 

January 2006

- ESD protection diode (note 3)
- RoHS Compliant



## Absolute Maximum Ratings T<sub>A=25°C</sub> unless otherwise noted

Symbol	Parameter		Ratings	Unit s
V <sub>DSS</sub>	Drain-Source Voltage		- 20	V
V <sub>GSS</sub>	Gate-Source Voltage		± 8	V
I <sub>D</sub>	Drain Current – Continuous	(Note 1a)	- 350	mA
	– Pulsed		- 1000	
PD	Power Dissipation (Steady State)	(Note 1a)	625	mW
		(Note 1b)	446	
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Junction Temperature Range		-55 to +150	°C

# Thermal Characteristics

R <sub>eJA</sub>	Thermal Resistance, Junction-to-Ambient (Note 1a)	200	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction-to-Ambient (Note 1b)	280	

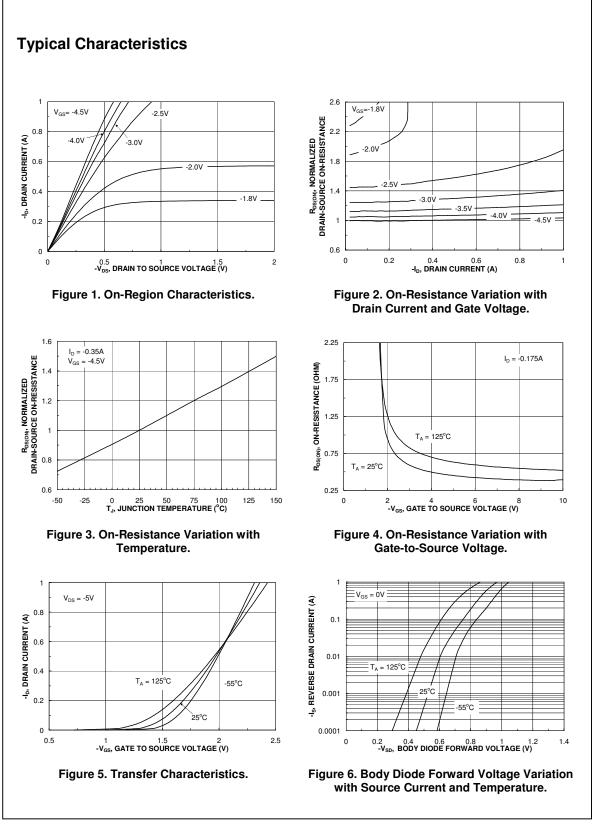
# Package Marking and Ordering Information

Device Marking	Device	Reel Size	Tape width	Quantity
A	FDY2000PZ	7 "	8 mm	3000 units

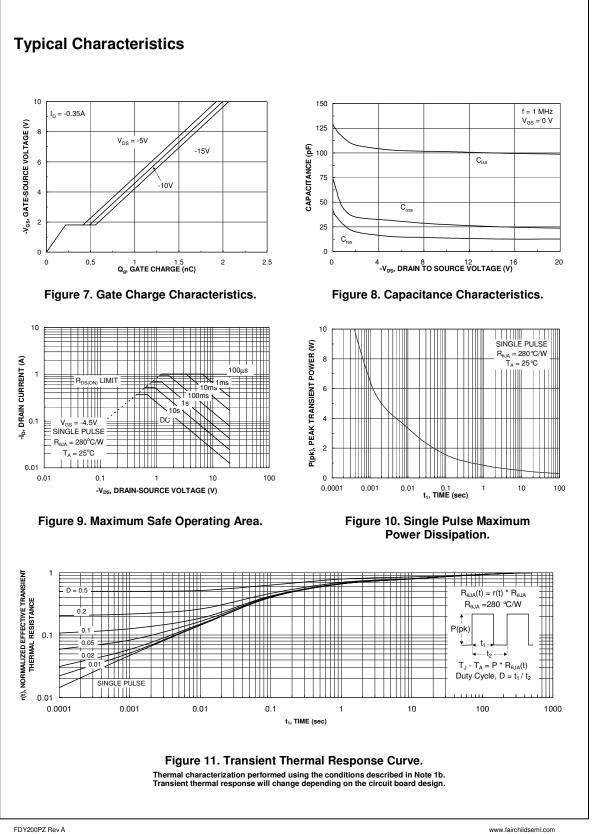
A, Referenced to 25°C $V_{\rm GS} = 0 V$ $V_{\rm DS} = 0 V$	- 20	-1.03 -3	- 3 ± 10 - 1.5	V mV/°C μΑ μΑ
A, Referenced to 25°C $V_{DS} = 0 V$ $V_{DS} = 0 V$ $I_D = -250 \mu A$ Referenced to 25°C $V, I_D = -350 m A$ $V, I_D = -300 m A$ $V, I_D = -150 m A$		-1.03	± 10	mV/°C μA
$V_{,} V_{GS} = 0 V$ $V_{DS} = 0 V$ $I_{D} = -250 \mu A - Referenced to 25°C$ $V, I_{D} = -350 m A$ $V, I_{D} = -300 m A$ $V, I_{D} = -150 m A$	- 0.65 -	-1.03	± 10	
$V_{DS} = 0 V$ $I_{D} = -250 \mu A$ Referenced to 25°C $V, I_{D} = -350 mA$ $V, I_{D} = -300 mA$ $V, I_{D} = -150 mA$	- 0.65 -		± 10	
$I_{D} = -250 \ \mu A \qquad -$ Referenced to 25°C V, I_{D} = -350 mA V, I_{D} = -300 mA V, I_{D} = -150 mA	- 0.65 -			μA V
Referenced to 25°C V, $I_D = -350 \text{ mA}$ V, $I_D = -300 \text{ mA}$ V, $I_D = -150 \text{ mA}$	- 0.65 -		- 1.5	V
Referenced to 25°C V, $I_D = -350 \text{ mA}$ V, $I_D = -300 \text{ mA}$ V, $I_D = -150 \text{ mA}$	- 0.65 -		- 1.5	V
V, $I_D = -350 \text{ mA}$ V, $I_D = -300 \text{ mA}$ V, $I_D = -150 \text{ mA}$		-3		•
V, $I_D = -300 \text{ mA}$ V, $I_D = -150 \text{ mA}$				mV/°C
$\mathbf{v}, \mathbf{n}_{\mathrm{D}} = -350 \mathrm{mA},$		0.5 0.8 1.3 0.7	1.2 1.6 2.7 1.6	Ω
$I_{\rm D} = -350 \text{ mA}$		1.04		S
$V_{\rm GS} = 0 V_{\rm C}$		100		pF
		30		pF
1		15		pF
/ la = = 0.5 A		6	12	ns
				ns
		-	-	ns
				ns
/ la = = 350 mA				nC
V				nC
-				nC
		0.0		
<u> </u>		0.0	10	V
$I_{\rm S} = -150$ III A (Note 2)		- 0.0	- 1.2	v
A,		10		ns
A/µs		1.5		nC
i	V, $V_{GS} = 0$ V, V, $I_D = -0.5$ A, V, $R_{GEN} = 6 \Omega$ V, $I_D = -350$ mA, V imum Ratings $I_S = -150$ m A (Note 2) A, $A/\mu s$ vhere the case thermal reference is r's board design	V, $I_D = -0.5 A$ , V, $R_{GEN} = 6 Ω$	30         30         15         V, $I_D = -0.5 A$ ,         V, $R_{GEN} = 6 \Omega$ 13         8         1         V, $I_D = -350 \text{ mA}$ ,         0.2         0.3         Imum Ratings $I_S = -150 \text{ m A (Note 2)}$ -0.8         nA,         A/µs         1.5	30         30         15 $\chi$ , $I_D = -0.5 A$ , $V$ , $R_{GEN} = 6 \Omega$ 13       23         8       16         1       2 $\chi$ , $I_D = -350 \text{ mA}$ ,       1.0       1.4 $V$ 0.2       0.3         Imum Ratings       -0.8       -1.2 $I_S = -150 \text{ m A (Note 2)}$ -0.8       -1.2 $IA$ ,       10       A/µs         vhere the case thermal reference is defined as the solder mounting

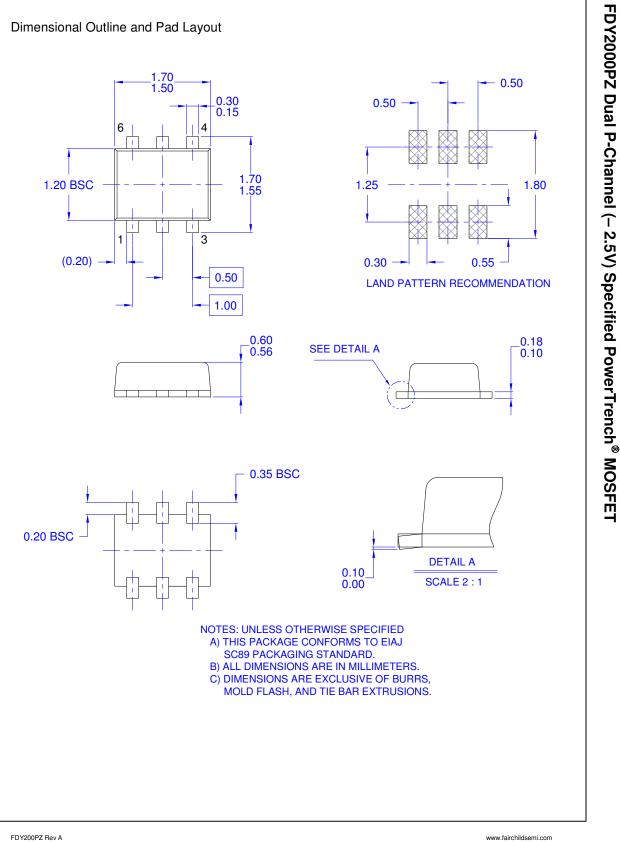
FDY2000PZ Dual P-Channel (– 2.5V) Specified PowerTrench<sup>®</sup> MOSFET

FDY200PZ Rev A



FDY200PZ Rev A





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